**IRU3004**

# 5-BIT PROGRAMMABLE SYNCHRONOUS BUCK CONTROLLER IC WITH DUAL LDO CONTROLLER

### **FEATURES**

- Meets latest VRM 8.4 specification for PentiumIII
- Provides single chip solution for Vcore, GTL+ and clock supply
- On-Board DAC programs the output voltage from  $\blacksquare$ 1.3V to 3.5V. The IRU3004 remains on for VID code of (11111)
- Dual linear regulator controller on-board for 1.5V GTL+ and 2.5V clock supplies
- Loss-less Short Circuit Protection
- $\blacksquare$ Synchronous operation allows maximum efficiency
- Patented architecture allows fixed frequency operation as well as 100% duty cycle during dynamic load
- $\blacksquare$ Minimum Part Count, No External Compensation
- $\blacksquare$ Soft-Start Function
- High current totem pole driver for direct driving of the external power MOSFET
- Power Good Function

### **APPLICATIONS**

- Pentium III & next generation processor DC to DC converter application
- Low Cost Pentium with AGP

### **DESCRIPTION**

The IRU3004 controller IC is specifically designed to meet Intel specifications for Pentium III™ microprocessor applications as well as the next generation P6 family processors. The IC provides a single chip controller IC for the Vcore, GTL+ and clock supplies required for the Pentium III applications. The IRU3004 features a patented topology, that in combination with a few external components as shown in the typical application circuit, will provide in excess of 20A of output current for an onboard DC-DC converter while automatically providing the right output voltage via the 5-bit internal DAC meeting the latest VRM specification. The IRU3004 also features loss-less current sensing by using the R<sub>DS(on)</sub> of the high side power MOSFET as the sensing resistor and a Power Good window comparator that switches its open collector output low when the output is outside of a  $\pm 10\%$ window. Other features of the device are: under-voltage lockout for both 5V and 12V supplies, an external programmable soft-start function as well as programming the oscillator frequency by using an external capacitor.



## **PACKAGE ORDER INFORMATION**



# **ABSOLUTE MAXIMUM RATINGS**



# **PACKAGE INFORMATION**



# **ELECTRICAL SPECIFICATIONS**

Unless otherwise specified, these specifications apply over V12=12V, V5=5V and TA=0 to 70°C. Typical values refer to T<sub>A=25</sub>°C. Low duty cycle pulse testing is used which keeps junction and case temperatures equal to the ambient temperature.





**Note 1:** Vs refers to the set point voltage given in Table 1.



Table 1 - Set point voltage vs. VID codes.

## **PIN DESCRIPTIONS**



# **BLOCK DIAGRAM**



Figure 2 - Simplified block diagram of the IRU3004.

# **TYPICAL APPLICATION**

**Pentium III**



Figure 3 - Typical application of IRU3004 in an on-board DC-DC converter providing the Core, GTL+, and Clock supplies for the Pentium II microprocessor.

# **IRU3004 APPLICATION PARTS LIST**



**Note 1:** R16, R17, C16, R12, and R13 set the Vcore 2% higher for level shift to reduce CPU transient voltage.

**Note 2:** R14 and R15 set the 1.5V approximately 1% higher to account for the trace resistance drop.

# **TYPICAL APPLICATION**

Pentium with AGP



Figure 4 - Typical application of IRU3004 in a Pentium with AGP where the power dissipation of the 3.3V linear regulator is equally distributed between Q3 and Q4 pass transistors. This equal distribution is possible by accurately regulating the first regulator using the IRU3004 linear controller and its internal 1% reference voltage while the second controller regulates the output of the first regulator from 4.17V to 3.3V, thereby distributing the power dissipation equally.

# **IRU3004 APPLICATION PARTS LIST**



**Note 1:** R16, R17, C16, R12, and R13 set the Vcore 2% higher for level shift to reduce CPU transient voltage.

# **APPLICATION INFORMATION**

An example of how to calculate the components for the application circuit is given below.

Assuming, two sets of output conditions that this regulator must meet:

a) Vo=2.8V, Io=14.2A,  $\Delta$ Vo=185mV,  $\Delta$ Io=14.2A

b) Vo=2V, Io=14.2A,  $\Delta$ Vo=140mV,  $\Delta$ Io=14.2A

The regulator design will be done such that it meets the worst case requirement of each condition.

### **Output Capacitor Selection**

The first step is to select the output capacitor. This is done primarily by selecting the maximum ESR value that meets the transient voltage budget of the total  $\Delta V$ o specification. Assuming that the regulators DC initial accuracy plus the output ripple is 2% of the output voltage, then the maximum ESR of the output capacitor is calculated as:

$$
\text{ESR} \le \frac{100}{14.2} = 7 \text{m}\Omega
$$

The Sanyo MVGX series is a good choice to achieve both the price and performance goals. The 6MV1500GX,  $1500\mu$ F, 6.3V has an ESR of less than 36m $\Omega$  typical. Selecting 6 of these capacitors in parallel has an ESR of  $\approx$  6m $\Omega$  which achieves our low ESR goal.

Other type of Electrolytic capacitors from other manufacturers to consider are the Panasonic FA series or the Nichicon PL series.

#### **Reducing the Output Capacitors Using Voltage Level Shifting Technique**

The trace resistance or an external resistor from the output of the switching regulator to the Slot 1 can be used to the circuit advantage and possibly reduce the number of output capacitors, by level shifting the DC regulation point when transition from light load to full load and vice versa. To accomplish this, the output of the regulator is typically set about half the DC drop that results from light load to full load. For example, if the total resistance from the output capacitors to the Slot 1 and back to the Gnd pin of the device is  $5m\Omega$  and if the total  $\Delta I$ , the change from light load to full load is 14A, then the output voltage measured at the top of the resistor divider which is also connected to the output capacitors in this case, must be set at half of the 70mV or 35mV higher than the DAC voltage setting. This intentional voltage level shifting during the load transient eases the requirement for the

output capacitor ESR at the cost of load regulation. One can show that the new ESR requirement eases up by half the total trace resistance. For example, if the ESR requirement of the output capacitors without voltage level shifting must be 7m $\Omega$ , then after level shifting the new ESR will only need to be  $9.5m\Omega$  if the trace resistance is  $5m\Omega$  (7 + 5/2=9.5). However, one must be careful that the combined "voltage level shifting" and the transient response is still within the maximum tolerance of the Intel specification. To insure this, the maximum trace resistance must be less than:

$$
\mathsf{Rs} \le 2 \times \frac{(\mathsf{Vspec} \cdot 0.02 \times \mathsf{Vo} \cdot \Delta \mathsf{Vo})}{\Delta \mathsf{I}}
$$

Where:

Rs = Total maximum trace resistance allowed Vspec = Intel total voltage specification Vo = Output voltage  $\Delta$ Vo = Output ripple voltage  $\Delta I$  = load current step

```
For example, assuming:
```
Vspec =  $\pm 140$ mV =  $\pm 0.1$ V for 2V output  $V_0 = 2V$  $\Delta$ Vo = assume 10mV = 0.01V  $\Delta I = 14.2A$ 

Then the Rs is calculated to be:

$$
\text{Rs} \le 2 \, \times \frac{(0.140 \text{ - } 0.02 \, \times \, 2 \text{ - } 0.01)}{14.2} = 12.6 \text{m}\Omega
$$

However, if a resistor of this value is used, the maximum power dissipated in the trace (or if an external resistor is being used) must also be considered. For example if  $\text{Rs}=12.6\text{m}\Omega$ , the power dissipated is:

$$
lo^2 \times Rs = 14.2^2 \times 12.6 = 2.54W
$$

This is a lot of power to be dissipated in a system. So, if the Rs=5m $\Omega$ , then the power dissipated is about 1W which is much more acceptable. If level shifting is not implemented, then the maximum output capacitor ESR was shown previously to be  $7m\Omega$  which translated to  $\approx 6$ of the  $1500\mu$ F, 6MV1500GX type Sanyo capacitors. With Rs=5m $\Omega$ , the maximum ESR becomes 9.5m $\Omega$  which is equivalent to  $\approx$  4 caps. Another important consideration is that if a trace is being used to implement the resistor, the power dissipated by the trace increases the case temperature of the output capacitors which could seriously effect the life time of the output capacitors.

### **Output Inductor Selection**

The output inductance must be selected such that under low line and the maximum output voltage condition, the inductor current slope times the output capacitor ESR is ramping up faster than the capacitor voltage is drooping during a load current step. However, if the inductor is too small, the output ripple current and ripple voltage become too large. One solution to bring the ripple current down is to increase the switching frequency, however that will be at the cost of reduced efficiency and higher system cost. The following set of formulas are derived to achieve the optimum performance without many design iterations.

The maximum output inductance is calculated using the following equation:

$$
L = ESR \times C \times \left( \frac{V_{IN(MIN)} - V_{O(MAX)}}{2 \times \Delta I} \right)
$$

Where:

 $V_{IN(MIN)} =$  Minimum input voltage  $Vo = 2.8V$ ,  $\Delta I = 14.2A$ 

$$
L = 0.006 \times 9000 \times \left(\frac{4.75 - 2.8}{2 \times 14.2}\right) = 3.7 \mu H
$$

Assuming that the programmed switching frequency is set at 200KHz, an inductor is designed using the Micrometals' powder iron core material. The summary of the design is outlined below:

The selected core material is Powder Iron, the selected core is T50-52D from Micro Metal wound with 8 turns of #16 AWG wire, resulting in  $3\mu$ H inductance with  $\approx 3m\Omega$ of DC resistance.

Assuming  $L=3\mu H$  and Fsw=200KHz (switching frequency), the inductor ripple current and the output ripple voltage is calculated using the following set of equations:

T ≡ Switching Period  $D \equiv D$ uty Cycle Vsw ≡ High side Mosfet ON Voltage  $R_{DS}$   $\equiv$  Mosfet On Resistance Vsync ≡ Synchronous MOSFET ON Voltage  $\Delta$ Ir ≡ Inductor Ripple Current  $\Delta$ Vo ≡ Output Ripple Voltage

$$
T = \frac{1}{Fsw}
$$
  
\n
$$
Vsw = Vsync = Io \times Ros
$$
  
\n
$$
D \approx \frac{Vo + Vsync}{Vw - Vsw + Vsync}
$$
  
\n
$$
Vsw = \frac{1}{Vw} = \frac{1}{Vsw + Vsync}
$$
  
\n
$$
V = \frac{1}{Vw} = \frac{1}{Vsw + Vsync}
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\n
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V = \frac{1}{Vsw + Vsync}
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$$
V = \frac{1}{Vsw + Vsync}
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\n
$$
V = \frac{1}{Vsw + Vsync}
$$

In our example for Vo=2.8V and 14.2A load, assuming IRL3103 MOSFET for both switches with maximum onresistance of 19m $\Omega$ , we have:

$$
T = \frac{1}{200000} = 5\mu s
$$
  
\n
$$
Vsw = Vsync = 14.2 \times 0.019 = 0.27V
$$
  
\n
$$
D \approx \frac{2.8 + 0.27}{5 - 0.27 + 0.27} = 0.61
$$
  
\n
$$
T_{ON} = 0.61 \times 5 = 3.1\mu s
$$
  
\n
$$
T_{OFF} = 5 - 3.1 = 1.9\mu s
$$
  
\n
$$
\Delta Ir = (2.8 + 0.27) \times \frac{1.9}{3} = 1.94A
$$
  
\n
$$
\Delta Vo = 1.94 \times 0.006 = 0.011V = 11mV
$$

### **Power Component Selection**

Assuming IRL3103 MOSFETs as power components, we will calculate the maximum power dissipation as follows:

For high-side switch the maximum power dissipation happens at maximum Vo and maximum duty cycle.

$$
D_{MAX} \approx \frac{(2.8 + 0.27)}{(4.75 - 0.27 + 0.27)} = 0.65
$$
  
\n
$$
P_{DH} = D_{MAX} \times 10^{2} \times R_{DS(MAX)}
$$
  
\n
$$
P_{DH} = 0.65 \times 14.2^{2} \times 0.029 = 3.8W
$$
  
\n
$$
R_{DS(MAX)} = Maximum R_{DS(ON)} \text{ of the MOSFET (125°C)}
$$

For synchronous MOSFET, maximum power dissipation happens at minimum Vo and minimum duty cycle.

$$
D_{\text{MIN}} \approx \frac{(2 + 0.27)}{(5.25 - 0.27 + 0.27)} = 0.43
$$
  
\n
$$
P_{\text{DS}} = (1 - D_{\text{MIN}}) \times 10^2 \times R_{\text{DS}(\text{MAX})}
$$
  
\n
$$
P_{\text{DS}} = (1 - 0.43) \times 14.2^2 \times 0.029 = 3.33 \text{W}
$$

### **Heat Sink Selection**

Selection of the heat sink is based on the maximum allowable junction temperature of the MOSFETS. Since we previously selected the maximum  $\text{P}_{\text{DS(0n)}}$  at 125°C, then we must keep the junction below this temperature. Selecting TO-220 package gives  $\theta_{\text{JC}}=1.8^{\circ}$ C/W (from the venders' data sheet) and assuming that the selected heat sink is black anodized, the heat-sink-to-case thermal resistance is  $\theta$ cs=0.05°C/W, the maximum heat sink temperature is then calculated as:

$$
Ts = T_J - P_D \times (0 \text{Jc} + 0 \text{cs})
$$
  
\n
$$
Ts = 125 - 3.82 \times (1.8 + 0.05) = 118^{\circ}\text{C}
$$

With the maximum heat sink temperature calculated in the previous step, the heat-sink-to-air thermal resistance  $(\theta_{SA})$  is calculated as follows:

Assuming  $Ta = 35^{\circ}C$ :

 $\Delta T = Ts - Ta = 118 - 35 = 83^{\circ}C$ Temperature Rise Above Ambient

$$
\theta_{SA} = \frac{\Delta T}{P_D} = \frac{83}{3.82} = 22^{\circ}C/W
$$

Next, a heat sink with lower  $\theta$ sa than the one calculated in the previous step must be selected. One way is to simply look at the graphs of the "Heat Sink Temp Rise Above the Ambient" vs. the "Power Dissipation" given in the heat sink manufacturers' catalog and select a heat sink that results in lower temperature rise than the one calculated in previous step. The following heat sinks from AAVID and Thermalloy meet this criteria.



Following the same procedure for the Schottky diode results in a heat sink with  $\theta_{SA}=25^{\circ}C/W$ . Although it is possible to select a slightly smaller heat sink, for simplicity, the same heat sink as the one for the high side MOSFET is also selected for the synchronous MOSFET.

### **Switcher Current Limit Protection**

The PWM controller uses the MOSFET Ros(ON) as the sensing resistor to sense the MOSFET current and compares to a programmed voltage which is set externally via a resistor (Rcs) placed between the drain of the MOSFET and the "CS+" terminal of the IC as shown in the application circuit. For example, if the desired current limit point is set to be 22A and from our previous selection, the maximum MOSFET R<sub>DS(ON)</sub>=19m $\Omega$ , then the current sense resistor, Rcs is calculated as:

Where:  $I_B = 200 \mu A$  is the internal current setting of the device

$$
Vcs = IcL \times Ros = 22 \times 0.019 = 0.418V
$$

$$
Rcs = \frac{Vcs}{Is} = \frac{0.418V}{200 \mu A} = 2.1 K\Omega
$$

### **Switcher Timing Capacitor Selection**

The switching frequency can be programmed using an external timing capacitor. The value of Ct can be approximated using the equation below:

$$
Fsw \text{ y } \frac{3.5 \times 10^{-5}}{Ct}
$$

Where: Ct = Timing Capacitor Fsw = Switching Frequency

If  $Fsw = 200KHz$ :

Ct **y**  $\frac{3.5 \times 10^{-5}}{200 \times 10^{3}}$  = 175pF

### **LDO Power MOSFET Selection**

The first step in selecting the power MOSFET for the linear regulators is to select its maximum  $R_{DS(ON)}$  based on the input to output Dropout voltage and the maximum load current.

For Vo = 1.5V, 
$$
V_{IN} = 3.3V
$$
 and  $I_L = 2A$ :

$$
R_{DS(max)}\,=\,\,\frac{(V_{IN}-V_{O})}{I_{L}}=\,\frac{(3.3-1.5)}{2}=0.9\Omega
$$

Note that since the MOSFETs R<sub>DS(ON)</sub> increases with temperature, this number must be divided by  $\approx 1.5$ , in order to find the Ros(on) max at room temperature. The Motorola MTP3055VL has a maximum of 0.18 $\Omega$  RDS(ON) at room temperature, which meets our requirement.

To select the heat sink for the LDO MOSFET the first step is to calculate the maximum power dissipation of the device and then follow the same procedure as for the switcher.

$$
P_D = (V_{IN} - V_0) \times I_L
$$

Where:

 $P<sub>D</sub>$  = Power Dissipation of the Linear Regulator  $I_L$  = Linear Regulator Load Current

For the 1.5V and 2A load:

$$
P_D = (3.3 - 1.5) \times 2 = 3.6W
$$

Assuming  $T_{J(max)} = 125^{\circ}C$  then:

$$
Ts = T_J - P_D \times (0 \text{J}c + 0 \text{cs})
$$
  
\n
$$
Ts = 125 - 3.6 \times (1.8 + 0.05) = 118^{\circ}\text{C}
$$

With the maximum heat sink temperature calculated in the previous step, the heat-sink-to-air thermal resistance  $(θ<sub>SA</sub>)$  is calculated as follows:

Assuming  $Ta = 35^{\circ}C$ :

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 $\Delta T = Ts - Ta = 118 - 35 = 83^{\circ}C$ Temperature Rise Above Ambient

$$
\theta_{SA} = \frac{\Delta T}{P_D} = \frac{83}{3.6} = 23^{\circ}C/W
$$

The same heat sink as the one selected for the switcher MOSFETs is also suitable for the 1.5V regulator. It is also possible to use TO-263 package or even the MTD3055VL in D-Pak if the load current is less than 1.5A. For the 2.5V regulator, since the dropout voltage is only 0.8V and the load current is less than 0.5A, for most applications, the same MOSFET without heat sink or for low cost applications, one can use PN2222A in TO-92 or SOT-23 package.

#### **LDO Regulator Component Selection**

Since the internal voltage reference for the linear regulators is set at 1.5V for all devices, there is no need to divide the output voltage for the 1.5V, GTL+ regulator.

For the 2.5V Clock supply, the resistor dividers are selected per following:

$$
\mathsf{Vo} = \left(1 + \frac{\mathsf{R}t}{\mathsf{R}_{\mathsf{B}}}\right) \times \mathsf{V}_{\mathsf{REF}}
$$

Where: Rt = Top resistor divider  $R_B$  = Bottom resistor divider  $Vref = 1.5V$  typical

Assuming Rt =  $100\Omega$ , for Vo = 2.5V:

$$
R_B = \frac{Rt}{\left(\frac{V_O}{V_{REF}}\right) - 1} = \frac{100}{\left(\frac{2.5}{1.5}\right) - 1} = 150\Omega
$$

For  $1.5V$  output, Rt can be shorted and R left open. However, it is recommended to leave the resistor dividers as shown in the typical application circuit so that the output voltage can be adjusted higher to account for the trace resistance in the final board layout.

It is also recommended that an external filter be added on the linear regulators to reduce the amount of the high frequency ripple at the output of the regulators. This can simply be done by the resistor capacitor combination as shown in the application circuit.

### **Disabling the LDO Regulators**

The LDO controllers can easily be disabled by connecting the feedback pins ( $V_{FB1}$  and  $V_{FB2}$ ) to a voltage higher than 1.5V such as 5V for all devices.

#### **Switcher Output Voltage Adjust**

As was discussed earlier, the trace resistance from the output of the switching regulator to the Slot 1 can be used to the circuit advantage and possibly reduce the number of output capacitors, by level shifting the DC regulation point when transitioning from light load to full load and vice versa. To account for the DC drop, the output of the regulator is typically set about half the DC drop that results from light load to full load. For example, if the total resistance from the output capacitors to the Slot 1 and back to the Gnd pin of the part is  $5m\Omega$  and if the total  $\Delta I$ , the change from light load to full load is 14A, then the output voltage measured at the top of the resistor divider which is also connected to the output capacitors in this case, must be set at half of the 70mV or 35mV higher than the DAC voltage setting. To do this, the top resistor of the resistor divider (R12 in the application circuit) is set at 100 $\Omega$ , and the R13 is calculated.

For example, if DAC voltage setting is for 2.8V and the desired output under light load is 2.835V, then R13 is calculated using the following formula:

$$
R13 = 100 \times \left(\frac{V_{\text{DAC}}}{(V_0 - 1.004 \times V_{\text{DAC}})}\right) \quad (\Omega)
$$
\n
$$
R13 = 100 \times \left(\frac{2.8}{(2.835 - 1.004 \times 2.800)}\right) = 11.76 K\Omega
$$
\n
$$
Seler 11.8 KQ 1%
$$

Select 11.8KV, 1%

**Note:** The value of the top resistor must not exceed 100 $\Omega$ . The bottom resistor can then be adjusted to raise the output voltage.

### **Soft-Start Capacitor Selection**

The soft-start capacitor must be selected such that during the start up, when the output capacitors are charging up, the peak inductor current does not reach the current limit threshold. A minimum of  $1\mu$ F capacitor insures this for most applications. An internal  $10\mu A$  current source charges the soft-start capacitor which slowly ramps up the inverting input of the PWM comparator VFB3. This insures the output voltage to ramp at the same rate as the soft-start cap thereby limiting the input current. For example, with  $1\mu$ F and the  $10\mu$ A internal current source the ramp up rate is  $(\Delta V/\Delta t) = (I/C) = 1 \text{V}/100 \text{ms}.$ Assuming that the output capacitance is  $9000\mu$ F, the maximum start up current will be:

 $I = 9000 \mu F \times (1V / 100 \text{ms}) = 0.09A$ 

### **Input Filter**

It is recommended to place an inductor between the system 5V supply and the input capacitors of the switching regulator to isolate the 5V supply from the switching noise that occurs during the turn on and off of the switching components. Typically an inductor in the range of 1 to  $3\mu$ H will be sufficient in this type of application.

### **Switcher External Shutdown**

The best way to shutdown the switcher is to pull down on the soft-start pin using an external small signal transistor such as 2N3904 or 2N7002 small signal MOSFET. This allows slow ramp up of the output, the same as the power up.

### **Layout Considerations**

Switching regulators require careful attention to the layout of the components, specifically power components since they switch large currents. These switching components can create large amount of voltage spikes and high frequency harmonics if some of the critical components are far away from each other and are connected with inductive traces. The following is a guideline of how to place the critical components and the connections between them in order to minimize the above issues.

Start the layout by first placing the power components:

- 1) Place the input capacitors C3 and the high side MOSFET, Q1 as close to each other as possible.
- 2) Place the synchronous MOSFET, Q2 and the Q1 as close to each other as possible with the intention that the source of Q1 and drain of the Q2 has the shortest length.
- 3) Place the snubber R4 & C7 between Q1 & Q2.
- 4) Place the output inductor, L2 and the output capacitors, C10 between the MOSFET and the load with output capacitors distributed along the slot 1 and close to it.
- 5) Place the bypass capacitors, C4 and C6 right next to 12V and 5V pins. C4 next to the 12V, pin 12 and C6 next to the 5V, pin 5.
- 6) Place the controller IC such that the PWM output drives, pins 9 and 11 are relatively short distance from gates of Q1 and Q2.
- 7) Place resistor dividers, R7 & R8 close to pin 3, R12 & R13 (see note) close to pin 14 and R14 and R15 (see note) close to pin 20.

**Note:** Although, the PWM controller does not require R12-15 resistors, and the feedback pins 3 and 14 can be directly connected to their respective outputs, they can be used to set the outputs slightly higher to account for any output drop at the load due to the trace resistance.

8) Place R11, C15, Q3 and C11 close to each other and do the same with R9, C14, Q4 and C12.

**Note:** It is better to place the linear regulator components close to the IC and then run a trace from the output of each regulator to its respective load such as 2.5V to the clock and 1.5V for GTL + termination. However, if this is not possible then the trace from the linear drive output pins, pins 2 and 20 must be routed away from any high frequency data signals. It is critical, to place high frequency ceramic capacitors close to the clock chip and termination resistors to provide local bypassing.

9) Place timing capacitor C1 close to pin 1 and soft start capacitor C2 close to pin 13.

### Component connections:

**Note:** It is extremely important that no data bus should be passing through the switching regulator section specifically close to the fast transition nodes such as PWM drives or the inductor voltage.

Using the 4 layer board, dedicate on layer to ground, another layer as the power layer for the 5V, 3.3V, Vcore, 1.5V and if it is possible for the 2.5V. Connect all grounds to the ground plane using direct vias to the ground plane. Use large low inductance/low impedance plane to connect the following connections either using component side or the solder side:

- a) C3 to Q1 Drain
- b) Q1 Source to Q2 Drain
- c) Q2 drain to L2
- d) L2 to the output capacitors, C10
- e) C10 to the slot 1
- f) Input filter L1 to the C3
- g) C9 to Q4 drain
- h) C12 to the Q4 source

Connect the rest of the components using the shortest connection possible.

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NOTE: ALL MEASUREMENTS ARE IN MILLIMETERS.



<b>SYMBOL</b>	20-PIN	
	<b>MIN</b>	MAX
Α	12.598	12.979
B	1.018	1.524
С	0.66 REF	
D	0.33	0.508
E	7.40	7.60
F	2.032	2.64
G	0.10	0.30
ı	0.229	0.32
J	10.008	10.654
Κ	0°	8°
L	0.406	1.270
R	0.63	0.89
	2.337	2.642

NOTE: ALL MEASUREMENTS ARE IN MILLIMETERS.

## **PACKAGE SHIPMENT METHOD**







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